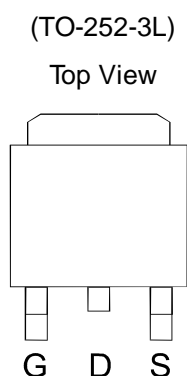


P- Channel 30-V (D-S) MOSFET

GENERAL DESCRIPTION

The ME20P03 is the P-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance. These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits , and low in-line power loss are needed in a very small outline surface mount package.

PIN CONFIGURATION

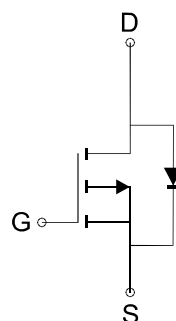


FEATURES

- $R_{DS(ON)} \leq 32m\Omega @ V_{GS} = -10V$
- $R_{DS(ON)} \leq 42m\Omega @ V_{GS} = -4.5V$
- Super high density cell design for extremely low $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability

APPLICATIONS

- Power Management in Note book
- DC/DC Converter
- Load Switch
- LCD Display inverter



P-Channel MOSFET

Ordering Information: ME20P03 (Pb-free)
ME20P03-G (Green product-Halogen free)

Absolute Maximum Ratings (Tc=25°C Unless Otherwise Noted)

Parameter	Symbol	Maximum Ratings	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	Tc=25°C	-27.6
		Tc=70°C	-25.5
Pulsed Drain Current	I_{DM}	-110	A
Maximum Power Dissipation	P_D	Tc=25°C	39
		Tc=70°C	25
Operating Junction Temperature	T_J	-55 to 150	°C
Thermal Resistance-Junction to Case*	$R_{\theta JC}$	3.2	°C/W

*The device mounted on 1in² FR4 board with 2 oz copper



P- Channel 30-V (D-S) MOSFET
Electrical Characteristics (T_c=25°C Unless Otherwise Specified)

Symbol	Parameter	Limit	Min	Typ	Max	Unit
STATIC						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =-250 μA	-30			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =-250 μA	-1		-3	V
I _{GSS}	Gate Leakage Current	V _{DS} =0V, V _{GS} =±20V			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =-24V, V _{GS} =0V			-1	μA
R _{DS(ON)}	Drain-Source On-State Resistance ^a	V _{GS} =-10V, I _D = -18A		27	32	mΩ
		V _{GS} =-4.5V, I _D = -10A		35	42	
V _{SD}	Diode Forward Voltage	I _S =-1A, V _{GS} =0V		-0.7	-1.2	V
DYNAMIC						
Q _g	Total Gate Charge(10V)	V _{DS} =-15V, V _{GS} =-4.5V, I _D =-18A		21		nC
Q _g	Total Gate Charge(4.5V)			10		
Q _{gs}	Gate-Source Charge			5		
Q _{gd}	Gate-Drain Charge			4.2		
C _{iss}	Input capacitance	V _{DS} =-15V, V _{GS} =0V, F=1MHz		804		pF
C _{oss}	Output Capacitance			123		
C _{rss}	Reverse Transfer Capacitance			40		
t _{d(on)}	Turn-On Delay Time	V _{DS} =-15V, R _L =15Ω I _D =-1A, V _{GEN} =-10V, R _G =3Ω		37		ns
t _r	Turn-On Rise Time			19		
t _{d(off)}	Turn-Off Delay Time			54		
t _f	Turn-Off Fall Time			7		

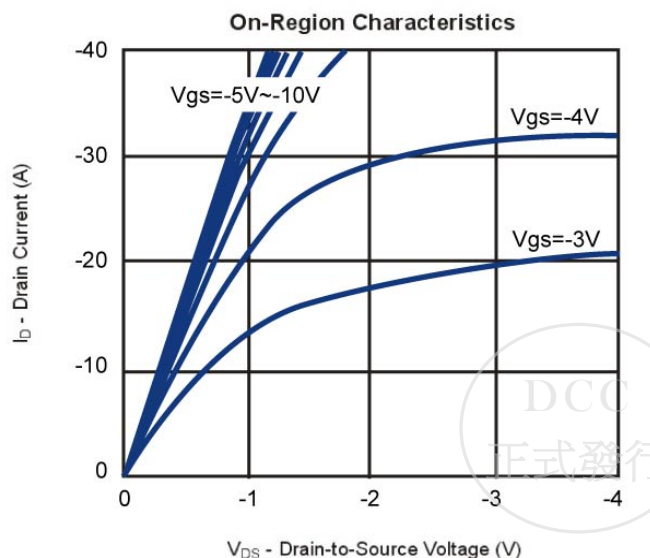
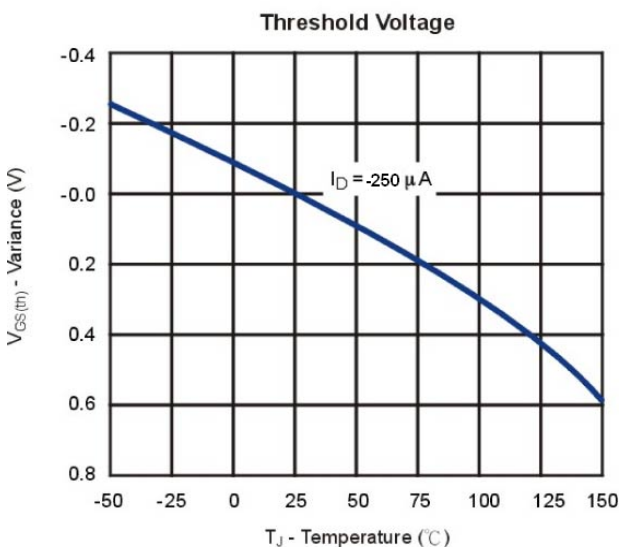
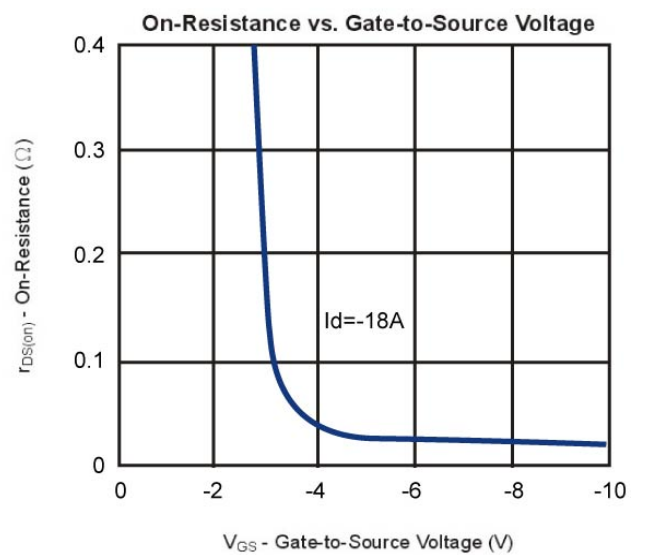
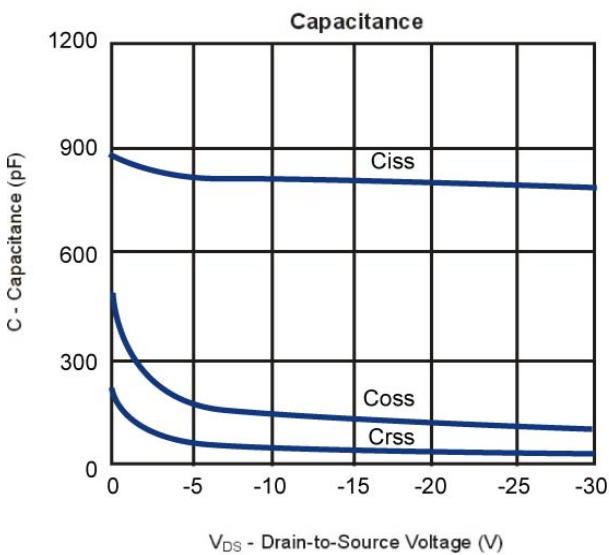
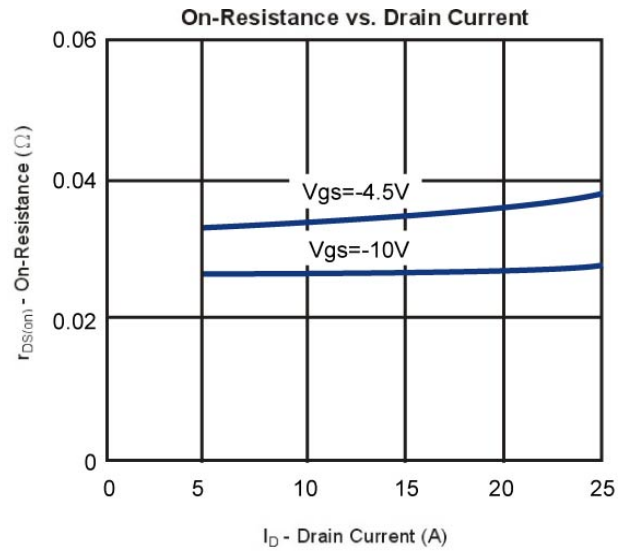
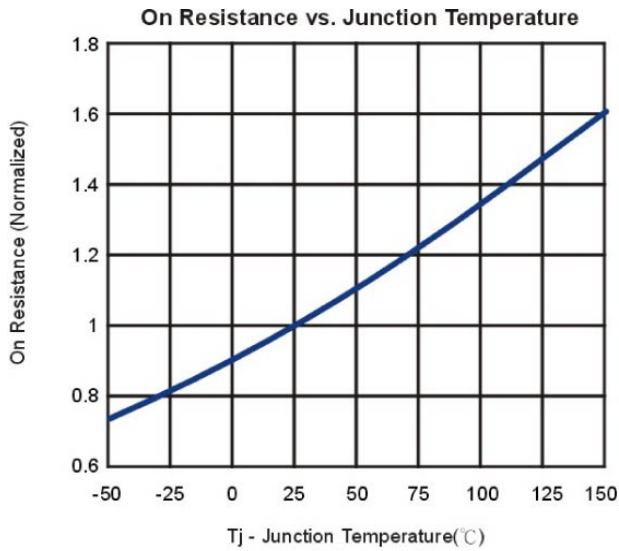
Notes:a. Pulse test; pulse width ≤ 300us, duty cycle ≤ 2%

b. Matsuki Electric/ Force mos reserves the right to improve product design, functions and reliability without notice.



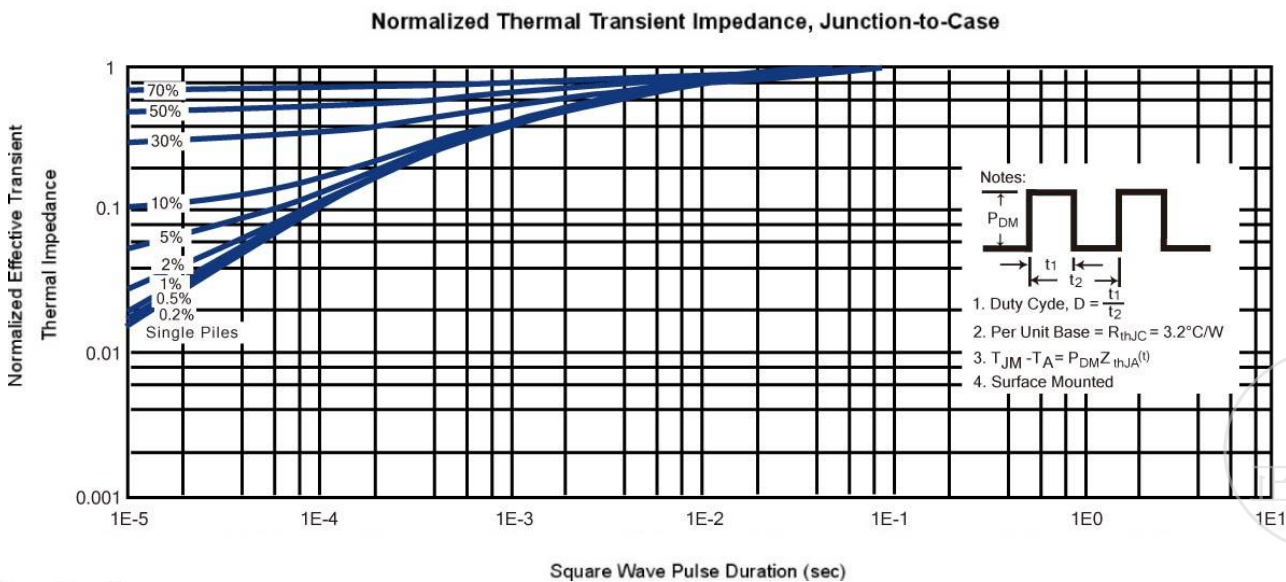
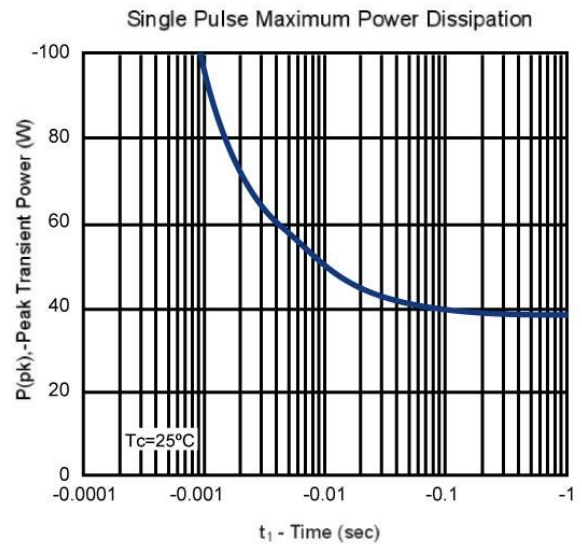
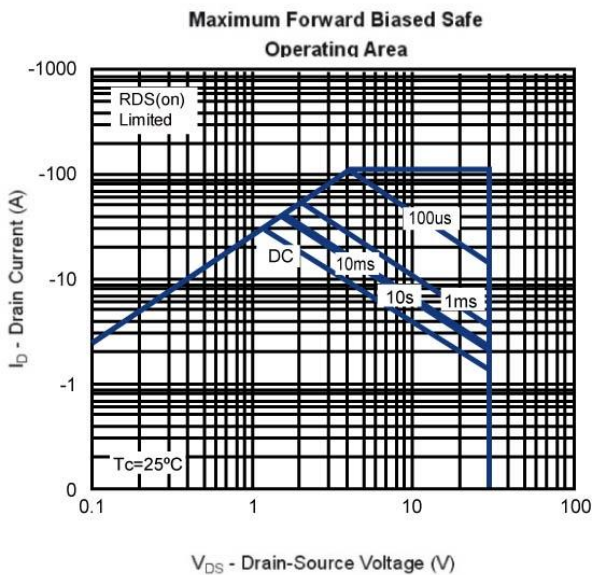
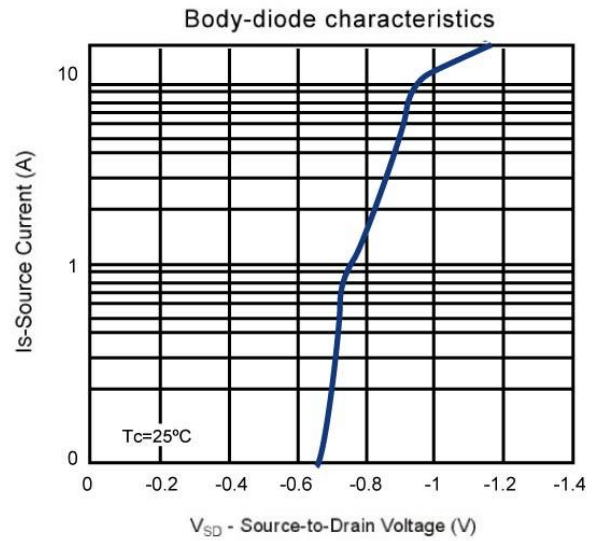
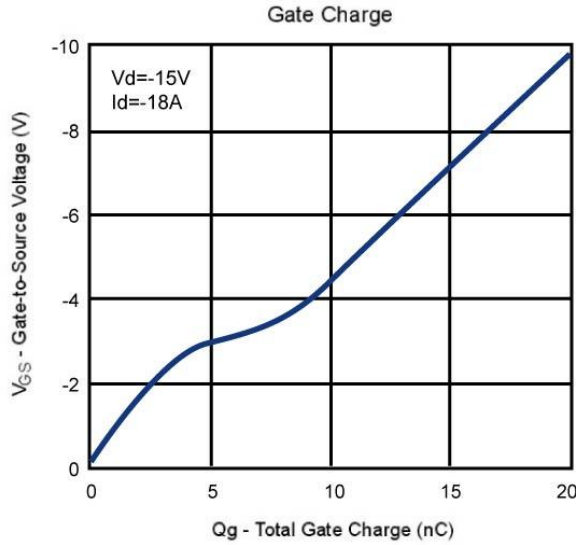
P- Channel 30-V (D-S) MOSFET

Typical Characteristics (T_J = 25°C Noted)



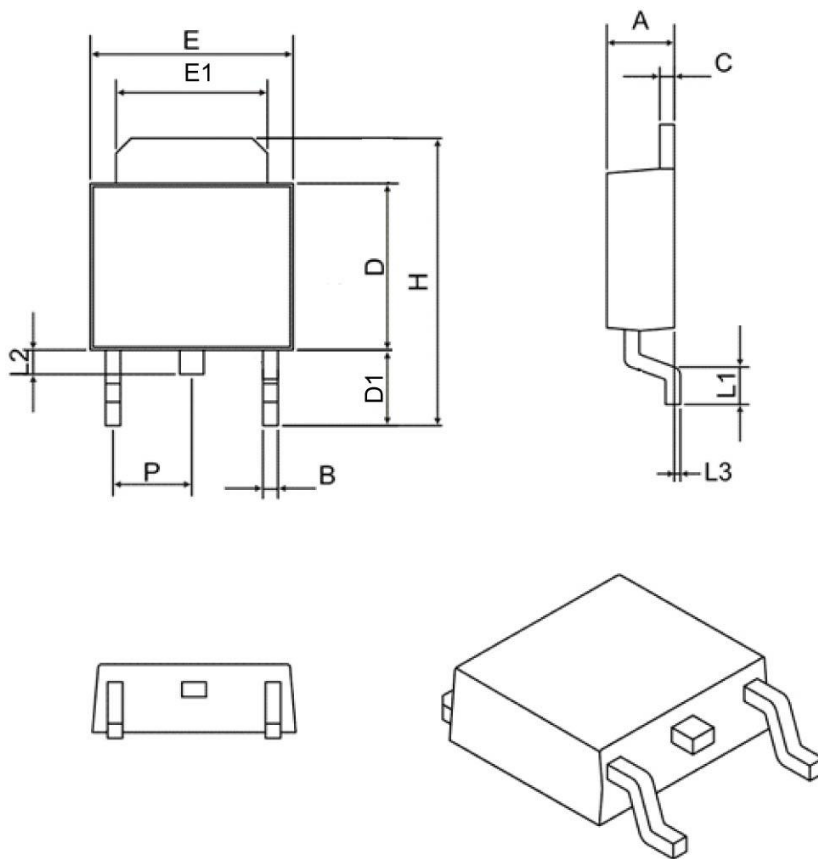
P- Channel 30-V (D-S) MOSFET

Typical Characteristics (T_J = 25°C Noted)



DCC
正式發行

TO-252 Package Outline



SYMBOL	MIN	MAX
A	2.10	2.50
B	0.40	0.90
C	0.40	0.90
D	5.30	6.30
D1	2.20	2.90
E	6.30	6.75
E1	4.80	5.50
L1	0.90	1.80
L2	0.50	1.10
L3	0.00	0.20
H	8.90	10.40
P	2.30 BSC	



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [MOSFET](#) category:

Click to view products by [MQTSUKI](#) manufacturer:

Other Similar products are found below :

[MCH3443-TL-E](#) [MCH6422-TL-E](#) [FDPF9N50NZ](#) [NTNS3A92PZT5G](#) [IRFD120](#) [JANTX2N5237](#) [2N7000](#) [2SK2464-TL-E](#) [AOD464](#) [2SJ277-DL-E](#) [2SK2267\(Q\)](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#) [MIC4420CM-TR](#) [VN1206L](#) [614234A](#) [715780A](#) [SSM6J414TU,LF\(T](#) [751625C](#)
[IRS2092STRPBF-EL](#) [IPS70R2K0CEAKMA1](#) [BSF024N03LT3 G](#) [PSMN4R2-30MLD](#) [TK31J60W5,S1VQ\(O](#) [2SK2614\(TE16L1,Q\)](#)
[DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [P85W28HP2F-7071](#) [DMN1053UCP4-7](#) [SQJ469EP-T1-GE3](#) [NTE2384](#) [NTE6400A](#)
[DMC2700UDMQ-7](#) [DMN2080UCB4-7](#) [DMN61D9UWQ-13](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [SSM6P54TU,LF](#) [DMP22D4UFO-7B](#)
[IPS60R3K4CEAKMA1](#) [DMN1006UCA6-7](#) [DMN16M9UCA6-7](#) [STF5N65M6](#) [IRF40H233XTMA1](#) [IPSA70R950CEAKMA1](#)
[IPSA70R2K0CEAKMA1](#) [STU5N65M6](#) [C3M0021120D](#) [DMN6022SSD-13](#)